Single pair of type-III Weyl points half-metals: BaNiIO₆ as an example

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The realization of Weyl systems with the minimum nonzero number of Weyl points (WPs) and full spin polarization remains challenging in topology physics and spintronic. In this paper, we used first-principles calculations and symmetry analysis to demonstrate that BaNiIO₆, a dynamically and thermodynamically stable half-metallic material, hosts fully spin-polarized single-pair (SP) WPs with a charge number (C) of ± 2 and a type-III band dispersion around the Fermi level. Moreover, the fully spin-polarized SP-WPs induce double-helicoid Fermi arcs on the (1010) surface. The half-metallic state and the spin-polarized SP-WPs are robust to uniform strains (from -10 to +8%) and onsite Hubbard-Coulomb interactions (from 0 to 6 eV). When +9 or +10% uniform strain is applied to the BaNiIO₆ system, it hosts six additional type-II WPs with |C| = 1 in the three-dimensional Brillouin zone in addition to the two type-III WPs with |C| = 2. We hope that this paper will motivate future research into SP-WPs half-metals.

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I. INTRODUCTION

Weyl semimetals [1-5] are crystals that host Weyl points (WPs) between two bands and have characteristic surface Fermi arcs in their electronic structure. Weyl semimetals can appear in solids when a material breaks either inversion symmetry [6-11], time-reversal symmetry [1,4,12,13], or both [14]. It would be highly preferable to realize Weyl semimetals with a minimum number of WPs to have a clean system to carefully study the properties of Weyl fermions. A minimum number of WPs will simplify the theoretical model and transport experiments [15]. Moreover, the surface states that arise from the minimum number of WPs can be easily imaged in spectroscopy experiments. However, if other crystal symmetry acts on the materials (i.e., rotates or reflects them), there can be many additional WPs in the systems; for example, there are 24 WPs in TaAs, TaP, NbAs, and NbP [6-9,16-19]; eight in MoTe₂ [20]; eight in chalcopyrites CuTlSe₂, AgTlTe₂, AuTITe₂, and ZnPbAs₂ [21]; and 60 in the stoichiometric compound $SrSi_2$ [22].

The well-known arguments are that four (two) is the minimum number of WPs allowed in a nonmagnetic (magnetic) Weyl semimetal [1,12,15,23–27]. However, these arguments are flawed, as demonstrated by our recent study [28], which revealed that nonmagnetic spinless systems can have only two WPs located at two high-symmetry time-reversal-invariant momenta (TRIMs). However, the minimum number of WPs at the TRIM for spinful systems should be eight because of the Kramers degeneracy at all eight TRIM points in the three-dimensional (3D) Brillouin zone (BZ).

An interesting question is whether an electronic system can have ferromagnetism, 100% spin polarization, and only two WPs at TRIM points. In this paper, we answer this question affirmatively. Herein, we propose single-pair (SP) WP halfmetals, a type of system that provides a simple platform for the interplay between magnetism and topological behaviors. The term SP refers to the minimal number of WPs (i.e., two) that should appear in a topological crystal in accordance with the no-go theorem [29,30]. Moreover, in this paper, we used a dynamically and mechanically stable material, BaNiIO₆ with space group *P*312 [No. 149], as an example to prove the theory behind half-metallicity, ferromagnetism, and SP-WPs at TRIM points.

Interestingly, our theoretical simulations on the spinpolarized band structures of BaNiIO₆ demonstrated that its WPs are unique in the following aspects. (1) There are only two WPs around the Fermi level (E_F) in the spin-up channel: a WP with a charge number (C) of 2 and another WP with C =-2, both of which are located at TRIM points A and Γ , respectively. The large separation between the two WPs (at A and Γ) allows the physics of the WPs to be exposed without intervention. (2) When spin-orbit coupling (SOC) is neglected, the SP-WPs proposed herein are completely formed by bands from the spin-up channel, making them 100% spin polarized.

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FIG. 1. (a) Crystal structure of the BaNiIO₆ unit cell. (b) Threedimensional (3D) bulk and two-dimensional (2D) (1010) surface Brillouin zones (BZs). (c) Phonon dispersion of BaNiIO₆. A $2 \times 2 \times 2$ supercell is adopted for the calculation of force constants. (d) Total energy fluctuation of a $3 \times 2 \times 2$ BaNiIO₆ supercell during *ab initio* molecular dynamics (AIMD) simulations at 300 K.

The fully spin-polarized fermions [31–41] may be helpful for spintronics applications. (3) The SP-WPs have a type-III band dispersion [42–45], implying that they host a unique Fermi surface consisting of two touching electronlike pockets. (4) The SP-WPs are robust to uniform strains and onsite Hubbard-Coulomb interactions.

II. MATERIAL EXAMPLE: BaNiIO₆

BaNiIO₆ is expected to crystallize in the trigonal P312space group [No. 149]. The experimental investigation of BaNiIO₆ may refer to that of the same mixed-metal periodate family [46,47]. Figure 1(a) depicts the crystal structure of BaNiIO₆ retrieved from the Materials Project database [48]. The derived lattice constants with the help of firstprinciples calculations of BaNiIO₆ are a = b = 5.186 Å and c = 5.857 Å. More details about the computational methods can be found in the Supplemental Material (SM) [49] (and Refs. [50–56] therein). Ba, Ni, I, and O are located at the 1*a*, 1d, 1f, and 6l Wyckoff sites in the structure, respectively. Table I shows that almost all the magnetic moments are localized around the Ni atoms, indicating that the Ni atoms are primarily responsible for the magnetic nature of BaNiIO₆. The atomic magnetic moments listed in Table I are computed by placing a sphere around each atom with the radius given in Table S1 (see SM [49]). Different magnetic configurations in the $1 \times 1 \times 2$ and $2 \times 2 \times 1$ supercells, including ferromagnetic, antiferromagnetic, and nonmagnetic config-

TABLE I. Total and atomic magnetic moments (μ_B) in the BaNiIO₆ unit cell.

Total	Ba	Ni	Ι	0
0.9991	0.007	0.742	0.03	0.032

urations, were considered to examine the magnetic ground state of BaNiIO₆ (see Figs. S1 and S2 in the SM [49]). The ferromagnetic state was discovered to have the lowest energy among all the magnetic configurations. In the following discussion, we only focus on the electronic structure and related topological signature of BaNiIO₆ with a ferromagnetic configuration.

Figure 1(c) depicts the phonon dispersion of BaNiIO₆ along the Γ -*M*-*K*- Γ -*A*-*L*-*H*-*A*|*L*-*M*|*H*-*K* high-symmetry paths, which was calculated using the density functional perturbation theory [54,55]. The phonon dispersion exhibits no imaginary modes, reflecting that it is dynamically stable. The thermodynamic stability of a $3 \times 2 \times 2$ BaNiIO₆ superlattice was tested using *ab initio* molecular dynamics (AIMD) simulation [56] at 300 K for 3 ps in a Nosé-Hoover thermostat ensemble. The results are shown in Fig. 1(d). During the simulation, the total energy was almost time invariant, and the geometric configuration did not suffer any noticeable disturbance, indicating that BaNiIO₆ is stable at room temperature.

III. ROBUST HALF-METALLIC BEHAVIOR

Figure 2(a) exhibits the calculated spin-polarized band structures and the density of states for BaNiIO₆ along the Γ -*M*-*K*- Γ -*A*-*L*-*H*-*A*|*L*-*M*|*H*-*K* high-symmetry paths. Noticeably, the band structures have two spin directions (highlighted by blue and red colors). The spin-up bands overlap with $E_{\rm F}$, indicating metallic behavior; however, the spin-down bands exhibit semiconducting behaviors since $E_{\rm F}$ is located between the large gap (~1.09 eV) formed by the lowest conduction band (CB) and the highest valence band (VB) of the spindown direction.

We calculated the spin-polarization ratio (P) of BaNiIO₆ based on the density of states using the following formula [57,58]:

$$P = \frac{\mathbf{N} \uparrow (E_{\mathrm{F}}) - \mathbf{N} \downarrow (E_{\mathrm{F}})}{\mathbf{N} \uparrow (E_{\mathrm{F}}) + \mathbf{N} \downarrow (E_{\mathrm{F}})},\tag{1}$$

where N \uparrow (*E*_F) and N \downarrow (*E*_F) are the spin-up and spin-down electrons at *E*_F, respectively. Since N \downarrow (*E*_F) = 0, BaNiIO₆ should have a full spin polarization around *E*_F. Moreover, as shown in Figs. 3(a) and S3(a) in the SM [49], the half-metallic behavior (i.e., 100% *P*) is maintained under different uniform strains (-10 to +10%) and different onsite Hubbard-Coulomb interactions (*U*_{Ni}) for the Ni-*d* orbital (0–6 eV).

As U_{Ni} changes from 0 to 6 eV, the semiconducting gap, which is the sum of the CB minimum (CBM) and the VB maximum (VBM) in the spin-down direction, increases from 1.09 to 2.56 eV (see Fig. S3(b) in the SM [49]). The halfmetallic gap, which is the smaller value between the absolute values of the CBM and VBM in the spin-down direction, can be viewed as an intuitive indicator of the robustness of the half-metallic behaviors. Figure S3(b) in the SM [49] shows that the half-metallic gap [59,60] in the spin-down direction increases, attains a maximum value (0.825 eV), and then decreases as the U_{Ni} changes from 0 to 6 eV.

Figure 3(b) depicts the relationship between the halfmetallic and semiconducting gaps and the uniform strains. Figure 3(b) shows that the semiconducting gap decreases



FIG. 2. (a) Spin-polarized band structures and density of states for the BaNiIO₆ ferromagnetic half-metal. dn and up represent the spindown and spin-up directions, respectively. The inset is a three-dimensional (3D) Fermi surface at the E_F . Note that the density of states for Ba and I are not plotted because they are zero around the Fermi level. (b) The 3D plot of the spin-up bands around the Weyl point (WP) at A in the k_x - k_y plane. (c) The 3D plot of the spin-up bands around the WP at A in the k_x - k_z plane. (d) Constant energy contour in the k_x - k_z plane at the energy of the WP at A. The blue regions in (d) represent the connected electronlike (*e*-like) pockets.

from 1.856 to 0.491 eV as the uniform strain changes from -10 to +10%. However, the half-metallic gap continuously increases, attains a maximum value (0.354 eV), and then decreases as the uniform strain changes from -10 to +10%.

IV. SPIN-POLARIZED SP OF TYPE-III WPS WITH |C| = 2

The spin-up bands around E_F are extremely clean. Specifically, only two doubly degenerate crossing points appear at the *A* and Γ TRIM points, and they are slightly above E_F [see the blue dots in Fig. 2(a)]. The inset of Fig. 2(a) is a 3D Fermi surface at E_F , demonstrating the appearance of the SP-WPs in 3D BZ. The density of states in Fig. 2(a) and the orbital-resolved band structures in Fig. S4 in the SM [49] demonstrate that the spin-up bands that form the SP-WPs are dominated by the Ni-*d* and O-*p* orbitals. Note that the SW-WPs can also be found in the spin-down channel (see Fig. S5 in the SM [49]), and they are also dominated by the Ni-*d* and O-*p* orbitals (see Fig. S6 in the SM [49]).

Furthermore, as illustrated in Fig. 4(b), the WP at A has C = +2, and the WP at Γ has C = -2 based on the evolutions of the average Wannier center positions [61,62]. Note that

the SP-WPs at the *A* and Γ TRIM points with |C| = 2 in the BaNiIO₆ system are strictly constrained by the no-go theorem [29,30]. Figure 4(a) illustrates the corresponding distribution of the Berry curvature in the k_x - k_z plane. The WP at *A*, which has C = +2, acts as the source point, while the WP at Γ , which has C = -2, acts as a sink point, resulting in the BaNiIO₆ system having a neutral chiral charge.

When SOC is neglected, the WPs with |C| = 2 at the *A* and Γ TRIM points are symmetry enforced. Figure 2(a) shows that the SP-WPs at the *A* and Γ TRIM points host a linear band dispersion along the k_z direction (i.e., the Γ -*A* path). However, the SP-WPs host a quadratic band dispersion in the k_x - k_y plane [see Fig. 2(b) for the example of the 3D plot of the bands around the WP at the *A* point in the k_x - k_y plane]. We display the 3D plot of the bands around the WP at the *A* point in the k_x - k_z plane as an example to clearly illustrate the type-III dispersion. The crossing bands possess a saddlelike dispersion. Figure 2(d) shows the constant energy surface at the WP (at the *A* point); there is a connection between two electronlike pockets.

When Γ_3 and A_3 , the irreducible corepresentations of space group P312, are considered, the $\mathbf{k} \cdot \mathbf{p}$ model can be easily obtained using the recently developed MAGENTICKP package



FIG. 3. (a) Conduction band minimum (CBM) and valence band maximum (VBM) as functions of uniform strains from -10 to +10%. The semiconducting gaps in the spin-down channel are highlighted by red and green backgrounds. The spin-polarized single-pair (SP) Weyl points (WPs) in the spin-up channel can be maintained from -10 to +8% uniform strains. However, eight spin-polarized WPs appear in the three-dimensional (3D) Brillouin zone (BZ) under +9 and +10% uniform strains. (b) Relationships between the uniform strains and the half-metallic/semiconducting gaps. Spin-polarized band structures of BaNiIO₆ under (c) -10% and (d) +8% uniform strains. (e) Spin-polarized band structure of BaNiIO₆ under +9% uniform strain. A doubly degenerate crossing point (W1) appears along the Γ -M path (in R1). (f) Enlarged spin-up bands of R1. Irreducible representations of the two bands around the W1 point on the Γ -M path are also exhibited. (g) The 3D plot of the bands around the type-II WP W1 in R1. (h) Constant energy contour in the k_x - k_y plane at the energy of the WP W1 in R1. The type-II dispersion hosts an electron-hole-like pocket Fermi surface. (i) Eight WPs (six type-II WPs and two type-III WPs) in the 3D BZ for BaNiIO₆ under +9% uniform strain.

[63,64]:

$$H = \varepsilon + \omega_{\parallel}k_{\parallel}^2 + \omega_z k_z^2 + v_z k_z \sigma_3 + [(ak_+^2 + bk_z k_+)\sigma_+ + \text{H.c.}], \qquad (2)$$

where $\sigma_i(i = 1, 2, 3)$ are three Pauli matrices, $\sigma_{\pm} = (\sigma_1 \pm \sigma_2)/2$ and ε , ω_{\parallel} , ω_z , v_z , a, b are real parameters, and $k_{\parallel}^2 = k_x^2 + k_y^2$. Note that *P*312 is a symmorphic space group, and the small cogroups of Γ , A are isomorphic to each other; therefore, such a model applies to both Γ_3 and A_3 . The dispersion on the $k_z = 0$ or π plane is $E(k_x, k_y) = \varepsilon + (\omega_{\parallel} \pm a)k_{\parallel}^2$. Thus, the Weyl cone for $|\omega_{\parallel}| > |a|$ can be over tilted, resulting in a

type-III WP. Table II shows the fitted parameters for $|\omega_{\parallel}|$ and |a| of the two bands around the two WPs at Γ and A, which confirm that the touching points at Γ and A are type-III WPs.

TABLE II. The fitted parameters for $|\omega_{\parallel}|$ and |a| of the two bands around the WPs at the Γ and A high-symmetry points.

High-symmetry points	a (eV Å ²)	$ \omega_{\parallel} (\mathrm{eV}\mathrm{\AA}^2)$	
Г	0.34	0.91	
Α	0.93	1.71	



FIG. 4. (a) Distribution of the Berry curvature in the $k_y = 0$ plane. (b) Evolutions of the average position of the Wannier center for the Weyl point (WP) with C = -2 at Γ and the WP with C = +2 at A. (c) Projected spectrum of the (1010) surface states of BaNiIO₆ along the $\overline{M} \cdot \overline{\Gamma} \cdot \overline{A} \cdot \overline{L}$ surface paths. (d) Energy slice for BaNiIO₆ corresponding to the (1010) surface at 0.045 eV [see the white dotted line in (c)]. The two spin-polarized surface states that arise from the spin-polarized single-point (SP)-WPs are marked by arrows.

It is interesting to note the following: (1) the SP-WPs in the BaNiIO₆ system are nearly affected by the SOC. Tables S2–S4 in the SM [49] show that BaNiIO₆ prefers the ferromagnetic state with the spin aligned along the [101] direction in the unit cell and $1 \times 1 \times 2$ and $2 \times 2 \times 1$ supercells, respectively, under SOC. Figure S7 in the SM [49] shows the band structures with SOC. Compared with the band structures without SOC [see Fig. 2(a)], the bands around E_F are almost unaffected by SOC. The SP-WPs at *A* and Γ are opened by SOC with a gap of <0.15 meV (Fig. S7 in the SM [49]), which is below the resolution of angle-resolved photoemission spectroscopy and significantly lower than the energy scale of room temperature (26 meV).

(2) Figure S3 in the SM [49] shows that the spin-polarized SP-WPs are robust to the onsite Hubbard-Coulomb interactions for the Ni-*d* orbital (U_{Ni} from 0 to 6 eV).

(3) The spin-polarized SP-WPs remain unchanged under uniform strains in the range of -10 to +8%. Figures 3(c) and 3(d) show examples of the spin-polarized band structures of BaNiIO₆ under -10 and +8% uniform strains, where the spin-polarized SP-WPs can be clearly observed. Interestingly, when we applied +9 and +10% uniform strains, the number of WPs in the BaNiIO₆ system increased from 2 to 8. The positions of the two type-III WPs (at *A* and Γ) under ambient conditions and uniform strains are shown in Fig. S8 (see SM [49]). The spin-polarized band structures of BaNiIO₆ under +9% uniform strain are shown in Fig. 3(e) as a typical example. Apart from the two crossing points at *A* and Γ , there is another doubly degenerate band crossing on the Γ -M path [see Fig. 3(f)]. Note that the crossing point on the Γ -M path has a type-II band dispersion [65–71] and |C| = 1. The type-II dispersion hosts an electron-hole-like pocket Fermi surface [see Fig. 3(h)] due to linearly tilted bands [see Fig. 3(g)]. As shown in Fig. 3(i), there are six type-II WPs with |C| = 1 and two type-III WPs with |C| = 2, resulting in a total of eight WPs in the 3D BZ.

When the direct sums of Σ_1 and Σ_2 irreducible corepresentations along the Γ -*M* are considered [see Fig. 3(f)], the $\mathbf{k} \cdot \mathbf{p}$ model for the degenerate points can be written as

$$H = \varepsilon + c_1 k_x + c_2 k_x \sigma_3 + [(\alpha k_y + \beta k_z)\sigma_+ + \text{H.c.}], \quad (3)$$

where ε , c_1 , c_2 are real parameters, and α , β are complex parameters. The band dispersion on the Γ -*M* line $(k_x = k_y = 0)$ is $H = \varepsilon + c_1k_x + c_2k_x\sigma_3$. Notably, when $|c_1| > |c_2|$, the tilt term dominates the band dispersion along Γ -*M*, forming a type-II WP. By fitting the parameters, we discovered that $|c_1| = 0.21$ (eV Å) and $|c_2| = 0.03$ (eV Å), confirming that the crossing point on Γ -*M* has a type-II band dispersion. The effects of SOC on the BaNiIO₆ system with +9 and +10% uniform strains are discussed in the SM (see Figs. S9 and S10) [49].

We would like to highlight that type-II and III WPs can exhibit many distinctive physical properties since most of the low-energy behaviors of systems in solids are usually determined by the geometry of the Fermi surface [42,72,73]. The coexistence of type-II and III WPs in a single solid may induce unique physical properties.

(4) In our recent work [28], we proposed that the surface Fermi arc for SP-WPs (in a nonmagnetic spinless system) is extended and exhibits a noncontractible winding topology on the surface BZ torus. Figures 4(c) and 4(d) depict the (1010) surface states of BaNiIO₆ along the \overline{M} - $\overline{\Gamma}$ - \overline{A} - \overline{L} surface paths and a constant energy slice at 0.045 eV, respectively. In contrast to the non-spin-polarized surface Fermi arc [74–79] in nonmagnetic SP-WPs systems, the two surface Fermi arcs that arise from the spin-polarized SP-WPs in BaNiIO₆ are fully spin polarized. Note that the Fermi arcs induced by the two type-III WPs on the (1010) surface can also be found when +9 or +10% uniform strain is applied (see Fig. S11 in the SM [49]).

(5) This study is an expansion of our previous study [28]. In our previous study, we stated that nonmagnetic spinless systems can host SP-WPs at two TRIM points and identified 32 candidate space groups (see table 1 in Ref. [28]) that host such a minimum number of WPs. In this paper, we mention that ferromagnetic half-metallic materials with negligible SOC (such as BaNiIO₆) are good platforms for realizing spin-polarized SP-WPs in their band structures. Since the ferromagnetic spin-up and spin-down bands have no symmetry connecting them, they can be considered separately when SOC is neglected. In other words, the bands for each spin direction can be viewed as spinless systems in principle. Hence, the proposed 32 candidate space groups in Ref. [28] can be used to search for SP-WPs half-metals (with negligible SOC) in the future.

V. SUMMARY AND REMARKS

We theoretically proposed a type-III SP-WPs half-metal using P312-type BaNiIO₆ as an example. Our first-principles calculations revealed that the spin-polarized SP of type-III WPs are localized at the Γ and A TRIM points in the first BZ and strictly follow the no-go theorem. Moreover, the metallic state in the spin-up direction and the semiconducting state in the spin-down direction cause BaNiIO₆ to exhibit a halfmetallic behavior with 100% spin polarization. The SP-WPs with $|\mathcal{C}| = 2$ induce two Fermi arcs with extended surface states that wind around the surface BZ along the k_z direction. The half-metallic state and the type-III SP-WPs in BaNiIO₆ are robust to the effect of uniform strains (from -10 to +8%) and onsite Hubbard-Coulomb interactions (from 0 to 6 eV). When +9 or +10% uniform strain was applied to the BaNiIO₆ system, the number of WPs increased from 2 to 8 in the 3D BZ. In such a case, there were eight WPs (six type-II WPs with $|\mathcal{C}| = 1$ and two type-III WPs with $|\mathcal{C}| = 2$) in the 3D BZ.

When SOC is neglected, the spin-up and spin-down channels in ferromagnetic half-metals are decoupled with a specific spin-polarization axis, making it possible to view the bands for each spin direction as spinless systems. Note that, in our previous work [28], we have already guided the search and design of nonmagnetic spinless systems with SP-WPs, and it can also be used as a guide to design SP-WPs ferromagnetic half-metals (with negligible SOC).

In this paper, we undoubtedly expand the scope of SP-WPs materials, propose the concept of type-III SP-WPs half-metals, and provide an example material, BaNiIO₆, for investigating their topological and spintronic properties.

- X. Wan, A. M. Turner, A. Vishwanath, and S. Y. Savrasov, Phys. Rev. B 83, 205101 (2011).
- [2] S. Murakami, New J. Phys. 9, 356 (2007).
- [3] A. A. Burkov and L. Balents, Phys. Rev. Lett. 107, 127205 (2011).
- [4] G. Xu, H. Weng, Z. Wang, X. Dai, and Z. Fang, Phys. Rev. Lett. 107, 186806 (2011).
- [5] C. Fang, M. J. Gilbert, X. Dai, and B. A. Bernevig, Phys. Rev. Lett. 108, 266802 (2012).
- [6] H. Weng, C. Fang, Z. Fang, B. A. Bernevig, and X. Dai, Phys. Rev. X 5, 011029 (2015).
- [7] S. M. Huang, S. Y. Xu, I. Belopolski, C. C. Lee, G. Q. Chang, B. K. Wang, N. Alidoust, G. Bian, M. Neupane, A. Bansil *et al.*, Nat. Commun. 6, 7373 (2015).
- [8] S.-Y. Xu, I. Belopolski, N. Alidoust, M. Neupane, G. Bian, C. Zhang, R. Sankar, G. Chang, Z. Yuan, C.-C. Lee *et al.*, Science 349, 613 (2015).
- [9] B. Q. Lv, H. M. Weng, B. B. Fu, X. P. Wang, H. Miao, J. Ma, P. Richard, X. C. Huang, L. X. Zhao, G. F. Chen *et al.*, Phys. Rev. X 5, 031013 (2015).
- [10] L. X. Yang, Z. K. Liu, Y. Sun, H. Peng, H. F. Yang, T. Zhang, B. Zhou, Y. Zhang, Y. F. Guo, M. Rahn *et al.*, Nat. Phys. **11**, 728 (2015).
- [11] A. A. Soluyanov, D. Gresch, Z. Wang, Q. Wu, M. Troyer, X. Dai, and B. A. Bernevig, Nature (London) 527, 495 (2015).

Note that we are intrigued by a recent study [45]. Li *et al.* [45] reported the experimental observation of type-III SP-WPs in nonmagnetic sonic crystals with space group No. 89 based on our previous work [28]. Therefore, we hope that this paper can provide ideas for researchers in the field of spin-tronics and topology physics. The experimental confirmation of the type-III SP-WPs half-metals is imminent.

The investigation of the topological signatures in halfmetals has been a hot research topic very recently. For example, one of the most known half-metals, CrO_2 , was theoretically demonstrated to host topological nodes [80], as effectively shown in the probed experimental band structure [81]. Moreover, the theoretical prediction of Cr_2C as a 2D half-metal hosting spin-polarized WPs has been reported by Meng *et al.* [82].

Finally, we would like to point out that $P6_322$ -type BaNiIO₆ is also a dynamically stable ferromagnetic halfmetal with eight WPs, formed by the crossings of bands 62 and 63, in theory (see Fig. S12 in the SM [49]). The detailed results of the half-metallic and topological properties for $P6_322$ -type BaNiIO₆ will be presented in a separate paper.

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- [12] N. P. Armitage, E. J. Mele, and A. Vishwanath, Rev. Mod. Phys. 90, 015001 (2018).
- [13] Z. Wang, M. G. Vergniory, S. Kushwaha, M. Hirschberger, E. V. Chulkov, A. Ernst, N. P. Ong, R. J. Cava, and B. A. Bernevig, Phys. Rev. Lett. **117**, 236401 (2016).
- [14] G. Chang, B. Singh, S.-Y. Xu, G. Bian, S.-M. Huang, C.-H. Hsu, I. Belopolski, N. Alidoust, D. S. Sanchez, H. Zheng *et al.*, Phys. Rev. B **97**, 041104(R) (2018).
- [15] I. Belopolski, P. Yu, D. S. Sanchez, Y. Ishida, T. R. Chang, S. S. Zhang, S. Y. Xu, H. Zheng, G. Chang, G. Bian *et al.*, Nat. Commun. 8, 942 (2017).
- [16] S.-Y. Xu, N. Alidoust, I. Belopolski, Z. Yuan, G. Bian, T.-R. Chang, H. Zheng, V. N. Strocov, D. S. Sanchez, G. Chang *et al.*, Nat. Phys. **11**, 748 (2015).
- [17] S. Y. Xu, I. Belopolski, D. S. Sanchez, C. Zhang, G. Chang, C. Guo, G. Bian, Z. Yuan, H. Lu, T.-R. Chang *et al.*, Sci. Adv. 1, e1501092 (2015).
- [18] H. Zheng, S.-Y. Xu, G. Bian, C. Guo, G. Chang, D. S. Sanchez, I. Belopolski, C.-C. Lee, S.-M. Huang, X. Zhang *et al.*, ACS Nano 10, 1378 (2016).
- [19] B. Q. Lv, N. Xu, H. M. Weng, J. Z. Ma, P. Richard, X. C. Huang, L. X. Zhao, G. F. Chen, C. E. Matt, F. Bisti, V. N. Strocov, J. Mesot, Z. Fang, X. Dai, T. Qian, M. Shi, and H. Ding, Nat. Phys. 11, 724 (2015).
- [20] Y. Sun, S.-C. Wu, M. N. Ali, C. Felser, and B. Yan, Phys. Rev. B 92, 161107(R) (2015).

- [21] J. Ruan, S.-K. Jian, D. Zhang, H. Yao, H. Zhang, S.-C. Zhang, and D. Xing, Phys. Rev. Lett. 116, 226801 (2016).
- [22] S.-M. Huang, S.-Y. Xu, I. Belopolski, C.-C. Lee, G. Chang, T.-R. Chang, B. Wang, N. Alidoust, G. Bian, M. Neupane *et al.*, Proc. Natl. Acad. Sci. USA **113**, 1180 (2016).
- [23] L. M. Schoop, F. Pielnhofer, and B. V. Lotsch, Chem. Mater. 30, 3155 (2018).
- [24] D. F. Liu, A. J. Liang, E. K. Liu, Q. N. Xu, Y. W. Li, C. Chen, D. Pei, W. J. Shi, S. K. Mo, P. Dudin *et al.*, Science **365**, 1282 (2019).
- [25] S. Nie, T. Hashimoto, and F. B. Prinz, Phys. Rev. Lett. 128, 176401 (2022).
- [26] L. Lu, L. Fu, J. D. Joannopoulos, and M. Soljačić, Nat. Photonics 7, 294 (2013).
- [27] O. Vafek and A. Vishwanath, Annu. Rev. Condens. Matter Phys. 5, 83 (2014).
- [28] X. Wang, F. Zhou, Z. Zhang, W. Wu, Z.-M. Yu, and S. A. Yang, Phys. Rev. B 106, 195129 (2022).
- [29] H. B. Nielsen and M. Ninomiya, Nucl. Phys. B 185, 20 (1981).
- [30] H. B. Nielsen and M. Ninomiya, Nucl. Phys. B 193, 173 (1981).
- [31] R.-W. Zhang, X. Zhou, Z. Zhang, D.-S. Ma, Z.-M. Yu, W. Feng, and Y. Yao, Nano Lett. 21, 8749 (2021).
- [32] T. Yang, L. Jin, Y. Liu, X. Zhang, and X. Wang, Phys. Rev. B 103, 235140 (2021).
- [33] J. Wang, H. Yuan, Y. Liu, X. Wang, and G. Zhang, Phys. Rev. B 106, L060407 (2022).
- [34] R.-W. Zhang, Z. Zhang, C.-C. Liu, and Y. Yao, Phys. Rev. Lett. 124, 016402 (2020).
- [35] X. Wang, Z. Cheng, G. Zhang, H. Yuan, H. Chen, and X.-L. Wang, Phys. Rep. 888, 1 (2020).
- [36] T. He, X. Zhang, L. Wang, Y. Liu, X. Dai, L. Wang, and G. Liu, Mater. Today Phys. 17, 100360 (2021).
- [37] H. Zhang, X. Zhang, T. He, X. Dai, Y. Liu, G. Liu, L. Wang, and Y. Zhang, Phys. Rev. B 102, 155116 (2020).
- [38] T. He, X. Zhang, Y. Liu, X. Dai, L. Wang, and G. Liu, Phys. Rev. B 104, 045143 (2021).
- [39] H. Zhang, X. Zhang, Y. Liu, X. Dai, G. Chen, and G. Liu, Phys. Rev. B 102, 195124 (2020).
- [40] C. Chen, Z.-M. Yu, S. Li, Z. Chen, X.-L. Sheng, and S. A. Yang, Phys. Rev. B 99, 075131 (2019).
- [41] J.-Y. You, C. Chen, Z. Zhang, X.-L. Sheng, S. A. Yang, and G. Su, Phys. Rev. B 100, 064408 (2019).
- [42] X.-P. Li, K. Deng, B. Fu, Y. Li, D.-S. Ma, J. F. Han, J. Zhou, S. Zhou, and Y. Yao, Phys. Rev. B 103, L081402 (2021).
- [43] L. Jin, X. Zhang, Y. Liu, X. Dai, L. Wang, and G. Liu, Phys. Rev. B 102, 195104 (2020).
- [44] G. Ding, F. Zhou, Z. Zhang, Z.-M. Yu, and X. Wang, Phys. Rev. B 105, 134303 (2022).
- [45] X.-P. Li, D. Zhou, Y. Wu, Z.-M. Yu, F. Li, and Y. Yao, Phys. Rev. B 106, L220302 (2022).
- [46] D. B. Currie, W. Levason, R. D. Oldroyd, and M. T. Weller, J. Mater. Chem. 3, 447 (1993).
- [47] I. D. Brown, Can. J. Chem. 47, 3779 (1969).
- [48] https://materialsproject.org/materials/mp-1147557.
- [49] See Supplemental Material at http://link.aps.org/supplemental/ 10.1103/PhysRevMaterials.7.014202 for the computational methods; energy comparison of FM, AFM, and NM states; band structures calculated by PBE + SOC, DFT +U, orbital-resolved spin-up and spin-down band structures; and the phonon

dispersion and spin-polarized band structures for $P6_322$ -type BaNiIO₆, etc., which includes Refs. [50–56].

- [50] P. E. Blöchl, Phys. Rev. B 50, 17953 (1994).
- [51] J. P. Perdew, K. Burke, and M. Ernzerhof, Phys. Rev. Lett. 80, 891 (1998).
- [52] Q. Wu, S. Zhang, H.-F. Song, M. Troyer, and A. A. Soluyanov, Phys. Chem. Commun. 224, 405 (2018).
- [53] A. A. Mostofi, J. R. Yates, Y.-S. Lee, I. Souza, D. Vanderbilt, and N. Marzari, Comput. Phys. Commun. 178, 685 (2008).
- [54] X. Gonze and C. Lee, Phys. Rev. B 55, 10355 (1997).
- [55] S. Baroni, P. Giannozzi, and A. Testa, Phys. Rev. Lett. 58, 1861 (1987).
- [56] M. E. Tuckerman, P. J. Ungar, T. Vonrosenvinge, and M. L. Klein, J. Phys. Chem. **100**, 12878 (1996).
- [57] Y. Sun, Z. Zhuo, X. Wu, and J. Yang, Nano Lett. **17**, 2771 (2017).
- [58] X. Wang, H. Khachai, R. Khenata, H. Yuan, L. Wang, W. Wang, A. Bouhemadou, L. Hao, X. Dai, R. Guo *et al.*, Sci. Rep. 7, 16183 (2017).
- [59] B. G. Liu, Phys. Rev. B 67, 172411 (2003).
- [60] G. Y. Gao, K. L. Yao, E. Şaşioğlu, L. M. Sandratskii, Z. L. Liu, and J. L. Jiang, Phys. Rev. B 75, 174442 (2007).
- [61] R. Yu, X. L. Qi, A. Bernevig, Z. Fang, and X. Dai, Phys. Rev. B 84, 075119 (2011).
- [62] D. Gresch, G. Autès, O. V. Yazyev, M. Troyer, D. Vanderbilt, B. A. Bernevig, and A. A. Soluyanov, Phys. Rev. B 95, 075146 (2017).
- [63] Z. Zhang, Z.-M. Yu, G.-B. Liu, Z. Li, S. A. Yang, and Y. Yao, arXiv:2205.05830 (2022).
- [64] G.-B. Liu, M. Chu, Z. Zhang, Z.-M. Yu, and Y. Yao, Comput. Phys. Commun. 265, 107993 (2021).
- [65] Y. Wu, D. Mou, N. H. Jo, K. Sun, L. Huang, S. L. Bud'ko, P. C. Canfield, and A. Kaminski, Phys. Rev. B 94, 121113(R) (2016).
- [66] Z. Wang, D. Gresch, A. A. Soluyanov, W. Xie, S. Kushwaha, X. Dai, M. Troyer, R. J. Cava, and B. A. Bernevig, Phys. Rev. Lett. 117, 056805 (2016).
- [67] P. Li, Y. Wen, X. He, Q. Zhang, C. Xia, Z.-M. Yu, S. A. Yang, Z. Zhu, H. N. Alshareef, and X.-X. Zhang, Nat. Commun. 8, 2150 (2017).
- [68] Z.-M. Yu, Y. Yao, and S. A. Yang, Phys. Rev. Lett. 117, 077202 (2016).
- [69] T. T. Zhang, Z.-M. Yu, W. Guo, D. Shi, G. Zhang, and Y. Yao, J. Phys. Chem. Lett. 8, 5792 (2017).
- [70] S. Li, Z.-M. Yu, Y. Liu, S. Guan, S.-S. Wang, X. Zhang, Y. Yao, and S. A. Yang, Phys. Rev. B 96, 081106(R) (2017).
- [71] S. Li, Z. M. Yu, Y. Yao, and S. A. Yang, Front. Phys. 15, 43201 (2020).
- [72] M. Udagawa and E. J. Bergholtz, Phys. Rev. Lett. 117, 086401 (2016).
- [73] T. E. O'Brien, M. Diez, and C. W. J. Beenakker, Phys. Rev. Lett. 116, 236401 (2016).
- [74] C. Cui, X.-P. Li, D.-S. Ma, Z.-M. Yu, and Y. Yao, Phys. Rev. B 104, 075115 (2021).
- [75] T. Zhang, Z. Song, A. Alexandradinata, H. Weng, C. Fang, L. Lu, and Z. Fang, Phys. Rev. Lett. **120**, 016401 (2018).
- [76] Q.-B. Liu, Z. Wang, and H.-H. Fu, Phys. Rev. B 103, L161303 (2021).
- [77] Z.-Q. Wang, Q.-B. Liu, X.-F. Yang, and H.-H. Fu, Phys. Rev. B 106, L161302 (2022).

- [78] M. Zhong, Y. Han, J. Wang, Y. Liu, X. Wang, and G. Zhang, Phys. Rev. Mater. 6, 084201 (2022).
- [79] P. C. Sreeparvathy, C. Mondal, C. K. Barman, and A. Alam, Phys. Rev. B 106, 085102 (2022).
- [80] R. Wang, Y. J. Jin, J. Z. Zhao, Z. J. Chen, Y. J. Zhao, and H. Xu, Phys. Rev. B 97, 195157 (2018).
- [81] F. Bisti, V. A. Rogalev, M. Karolak, S. Paul, A. Gupta, T. Schmitt, G. Guntherodt, V. Eyert, G. Sangiovanni, G. Profeta *et al.*, Phys. Rev. X 7, 041067 (2017).
- [82] W. Meng, X. Zhang, Y. Liu, L. Wang, X. Dai, and G. Liu, Appl. Surf. Sci. 540, 148318 (2021).